

TLV702-Q1 300-mA, Low- I_Q , Low-Dropout Regulator

1 Features

- Qualified for Automotive Applications
- AEC-Q100 Qualified with the Following Results:
 - Device Temperature Grade 1: -40°C to 125°C Ambient Operating Temperature Range
 - Device HBM ESD Classification Level H2
 - Device CDM ESD Classification Level C4B
- Very Low Dropout:
 - 37 mV at $I_{\text{OUT}} = 50\text{ mA}$, $V_{\text{OUT}} = 2.8\text{ V}$
 - 75 mV at $I_{\text{OUT}} = 100\text{ mA}$, $V_{\text{OUT}} = 2.8\text{ V}$
 - 220 mV at $I_{\text{OUT}} = 300\text{ mA}$, $V_{\text{OUT}} = 2.8\text{ V}$
- 2% Accuracy Over Temperature
- Low I_Q : 35 μA
- Fixed-Output Voltage Combinations Possible from 1.2 V to 4.8 V
- High PSRR: 68 dB at 1 kHz
- Stable with Effective Capacitance of 0.1 μF ⁽¹⁾
- Thermal Shutdown and Overcurrent Protection
- Packages: 5-Pin SOT (DBV and DDC) and 1.5-mm x 1.5-mm, 6-Pin WSON

⁽¹⁾ See the [Input and Output Capacitor Requirements](#) in the [Application Information](#) section.

2 Applications

- Automotive Camera Modules
- Image Sensor Power
- Microprocessor Rails
- Automotive Infotainment Head Units
- Automotive Body Electronics

3 Description

The TLV702-Q1 series of low-dropout (LDO) linear regulators are low quiescent current devices with excellent line and load transient performance. These LDOs are designed for power-sensitive applications.

A precision bandgap and an error amplifier provide overall 2% accuracy. Low output noise, very high power-supply rejection ratio (PSRR), and low-dropout voltage make this series of devices ideal for a wide selection of battery-operated equipment. All device versions have thermal shutdown and current limit protections for safety.

Furthermore, these devices are stable with an effective output capacitance of only 0.1 μF . This feature enables the use of cost-effective capacitors that have higher bias voltages and temperature derating. The devices regulate to specified accuracy with no output load.

The TLV702-Q1 series of LDO linear regulators is available in SOT and WSON packages.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TLV702-Q1	SOT (5)	2.90 mm x 1.60 mm
	WSON (6)	1.50 mm x 1.50 mm

⁽¹⁾ For all available packages, see the package option addendum at the end of the data sheet.

Typical Application

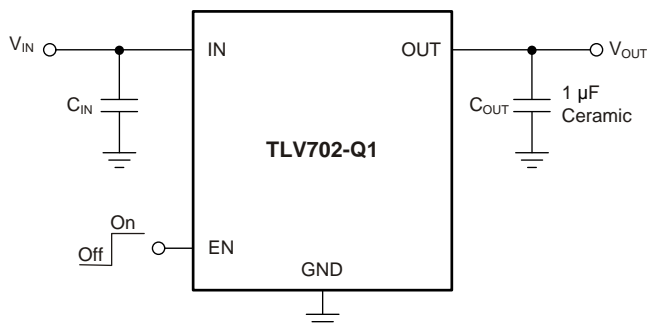


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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

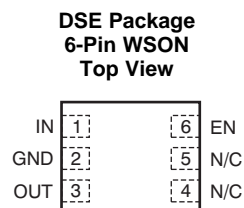
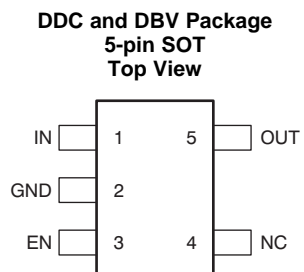
Changes from Revision C (January 2018) to Revision D	Page
• Changed OUT pin number from 5 to 3 in DSE column of <i>Pin Functions</i> table	4
• Added footnote to maximum EN voltage specification	5
• Added parameter names to <i>Recommended Operating Conditions</i> table.....	5

Changes from Revision B (June 2015) to Revision C	Page
• Added DBV package to document	1
• Changed <i>Packages</i> Features bullet to include DBV package	1
• Added DBV package to <i>Pin Configuration and Functions</i> section	4
• Added DBV column to <i>Thermal Information</i> table.....	5
• Changed title of <i>Layout Example for the DDC and DBV Packages</i> figure to include DBV package	16

Changes from Revision A (August 2013) to Revision B	Page
• Added DSE (6-Pin WSON) package to data sheet	1
• Added <i>Device Information</i> , <i>ESD Ratings</i> , and <i>Recommended Operating Conditions</i> tables, and <i>Detailed Description</i> , <i>Application and Implementation</i> , <i>Power Supply Recommendations</i> , <i>Layout</i> , <i>Device and Documentation Support</i> , and <i>Mechanical, Packaging, and Orderable Information</i> sections to data sheet	1
• Deleted all references to P version of device throughout data sheet.....	1
• Added "Over Temperature" to 2% accuracy <i>Features</i> bullet	1
• Changed DDC package name from TSOT23 to SOT throughout data sheet.....	1
• Changed <i>Applications</i> bullets	1
• Changed <i>Description</i> section text.....	1
• Changed ceramic capacitor units on <i>Typical Application</i> circuit from mF to μ F (typo)	1
• Changed "free-air temperature" to "junction temperature" in <i>Absolute Maximum Ratings</i> condition statement.....	5
• Added T_J to T_A condition in <i>Electrical Characteristics</i> condition statement.....	6

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- Changed T_A to T_J for typical values in *Electrcial Characteristics* condition statement 6
-

5 Pin Configuration and Functions



Pin Functions

NAME	PIN		I/O	DESCRIPTION
	DDC, DBV (SOT)	DSE (WSON)		
IN	1	1	I	Input pin. A small, 1- μ F ceramic capacitor is recommended from this pin to ground to assure stability and good transient performance. See Input and Output Capacitor Requirements in the <i>Application Information</i> section for more details.
GND	2	2	—	Ground pin
EN	3	6	I	Enable pin. Driving EN over 0.9 V turns on the regulator. Driving EN below 0.4 V puts the regulator into shutdown mode and reduces operating current to 1 μ A, nominal.
NC	4	4, 5	—	No connection. Tie this pin to ground to improve thermal dissipation.
OUT	5	3	O	Regulated output voltage pin. A small, 1- μ F ceramic capacitor is needed from this pin to ground for stability. See Input and Output Capacitor Requirements in the <i>Application Information</i> section for more details.

6 Specifications

6.1 Absolute Maximum Ratings

over operating junction temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Voltage ⁽²⁾	IN	–0.3	6	V
	EN	–0.3	6 ⁽³⁾	V
	OUT	–0.3	6	V
Current (source)	OUT	Internally limited		A
Output short-circuit duration		Indefinite		
Temperature	Operating virtual junction, T _J	–55	150	°C
	Storage, T _{stg}	–55	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltages are with respect to network ground terminal.
- (3) The absolute maximum rating is V_{IN} + 0.3 V or 6.0 V, whichever is smaller.

6.2 ESD Ratings

		VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per AEC Q100-002 ⁽¹⁾	±2000
		Charged-device model (CDM), per AEC Q100-011	±750

- (1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V _{IN}	Input voltage	2		5.5	V
V _{OUT}	Output voltage	1.2		4.8	V
I _{OUT}	Output current	0		300	mA
T _A	Ambient temperature	–40		125	°C
T _J	Operating virtual junction temperature	–40		125	°C

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		TLV702-Q1			UNIT
		DDC (SOT)	DBV (SOT)	DSE (WSON)	
		5 PINS	5 PINS	6 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	262.8	249.2	321.3	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	68.2	136.4	207.9	°C/W
R _{θJB}	Junction-to-board thermal resistance	81.6	85.9	281.5	°C/W
ψ _{JT}	Junction-to-top characterization parameter	1.1	19.5	42.4	°C/W
ψ _{JB}	Junction-to-board characterization parameter	80.9	85.3	284.8	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	N/A	142.3	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

6.5 Electrical Characteristics

At $V_{IN} = V_{OUT(nom)} + 0.5\text{ V}$ or 2 V (whichever is greater); $I_{OUT} = 10\text{ mA}$, $V_{EN} = 0.9\text{ V}$, $C_{OUT} = 1\text{ }\mu\text{F}$, and $T_J, T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$, unless otherwise noted. Typical values are at $T_J = 25^\circ\text{C}$.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
	DC output accuracy		-2%	0.5%	2%	
$\Delta V_{O(\Delta V)}$	Line regulation	$V_{OUT(nom)} + 0.5\text{ V} \leq V_{IN} \leq 5.5\text{ V}$, $I_{OUT} = 10\text{ mA}$		1	5	mV
$\Delta V_{O(\Delta I)}$	Load regulation	$0\text{ mA} \leq I_{OUT} \leq 300\text{ mA}$		1	15	mV
V_{DO}	Dropout voltage ⁽¹⁾	$V_{IN} = 0.98 \times V_{OUT(nom)}$, $I_{OUT} = 300\text{ mA}$		260	375	mV
I_{CL}	Output current limit	$V_{OUT} = 0.9 \times V_{OUT(nom)}$	320	500	860	mA
I_{GND}	Ground pin current	$I_{OUT} = 0\text{ mA}$		35	55	μA
		$I_{OUT} = 300\text{ mA}$, $V_{IN} = V_{OUT} + 0.5\text{ V}$		370		μA
I_{SHDN}	Ground pin current (shutdown)	$V_{EN} \leq 0.4\text{ V}$, $V_{IN} = 2\text{ V}$		400		nA
		$V_{EN} \leq 0.4\text{ V}$, $2\text{ V} \leq V_{IN} \leq 4.5\text{ V}$		1	2.5	μA
PSRR	Power-supply rejection ratio	$V_{IN} = 2.3\text{ V}$, $V_{OUT} = 1.8\text{ V}$, $I_{OUT} = 10\text{ mA}$, $f = 1\text{ kHz}$		68		dB
V_n	Output noise voltage	BW = 100 Hz to 100 kHz, $V_{IN} = 2.3\text{ V}$, $V_{OUT} = 1.8\text{ V}$, $I_{OUT} = 10\text{ mA}$		48		μV_{RMS}
t_{STR}	Start-up time ⁽²⁾	$C_{OUT} = 1\text{ }\mu\text{F}$, $I_{OUT} = 300\text{ mA}$		100		μs
$V_{EN(high)}$	Enable pin high (enabled)		0.9		V_{IN}	V
$V_{EN(low)}$	Enable pin low (disabled)		0		0.4	V
I_{EN}	Enable pin current	$V_{IN} = V_{EN} = 5.5\text{ V}$		0.04		μA
UVLO	Undervoltage lockout	V_{IN} rising		1.9		V
T_{sd}	Thermal shutdown temperature	Shutdown, temperature increasing		165		$^\circ\text{C}$
		Reset, temperature decreasing		145		$^\circ\text{C}$

(1) V_{DO} is measured for devices with $V_{OUT(nom)} \geq 2.35\text{ V}$.

(2) Start-up time = time from EN assertion to $0.98 \times V_{OUT(nom)}$.

6.6 Typical Characteristics

Over operating temperature range ($T_J = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$), $V_{IN} = V_{OUT(nom)} + 0.5\text{ V}$ or 2 V , whichever is greater; $I_{OUT} = 10\text{ mA}$, $V_{EN} = V_{IN}$, $C_{OUT} = 1\text{ }\mu\text{F}$, unless otherwise noted. Typical values are at $T_J = 25^{\circ}\text{C}$.

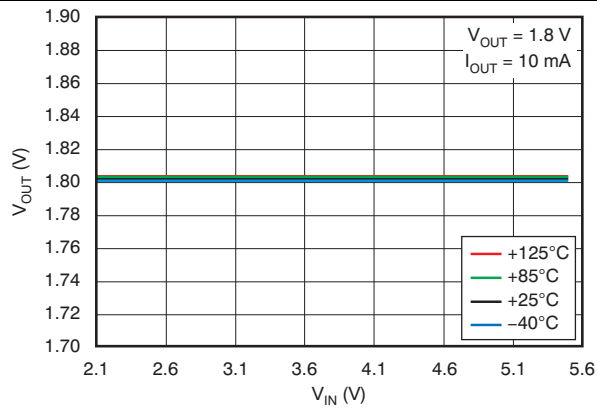


Figure 1. Line Regulation

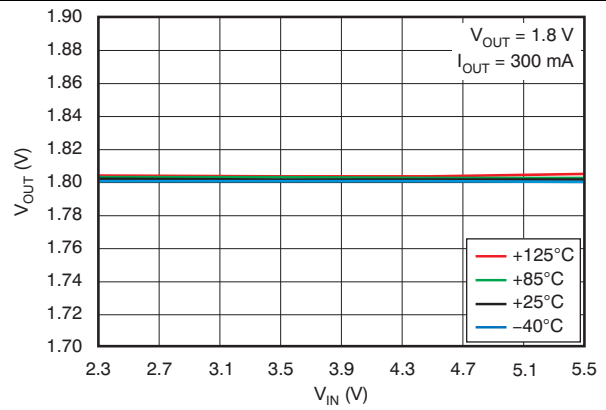


Figure 2. Line Regulation

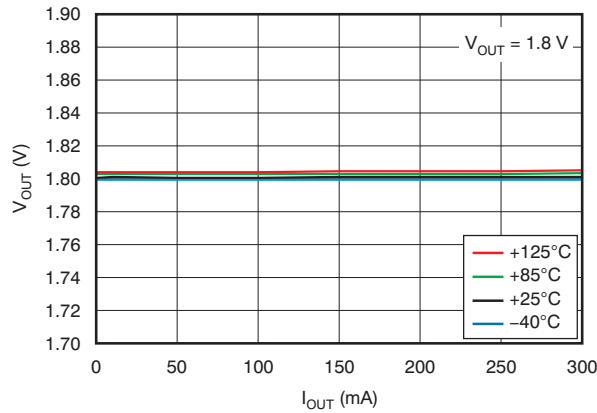


Figure 3. Load Regulation

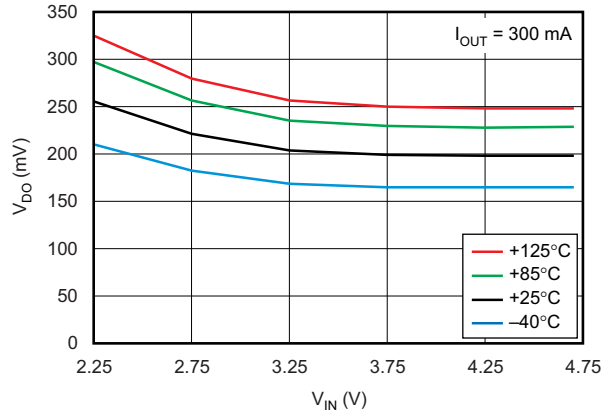


Figure 4. Dropout Voltage vs Input Voltage

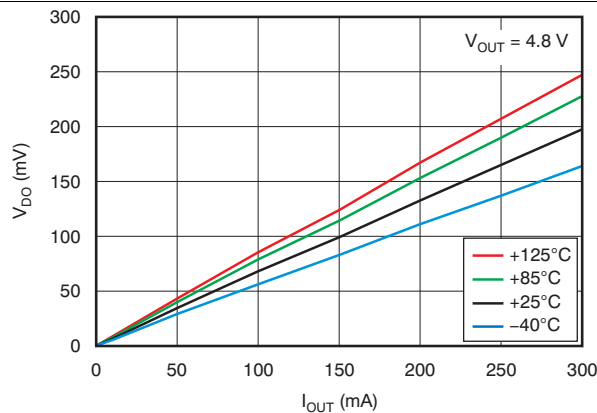


Figure 5. Dropout Voltage vs Output Current

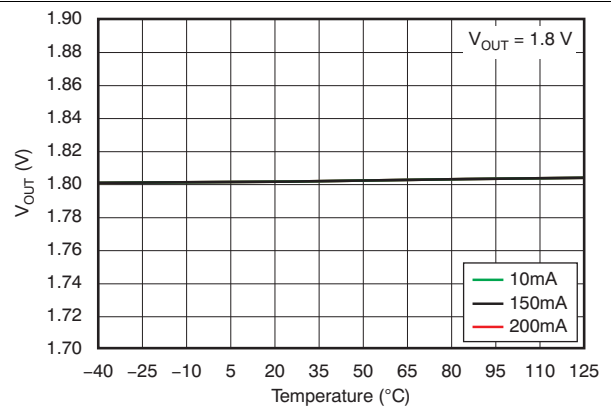


Figure 6. Output Voltage vs Temperature

Typical Characteristics (continued)

Over operating temperature range ($T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$), $V_{IN} = V_{OUT(nom)} + 0.5\text{ V}$ or 2 V , whichever is greater; $I_{OUT} = 10\text{ mA}$, $V_{EN} = V_{IN}$, $C_{OUT} = 1\ \mu\text{F}$, unless otherwise noted. Typical values are at $T_J = 25^\circ\text{C}$.

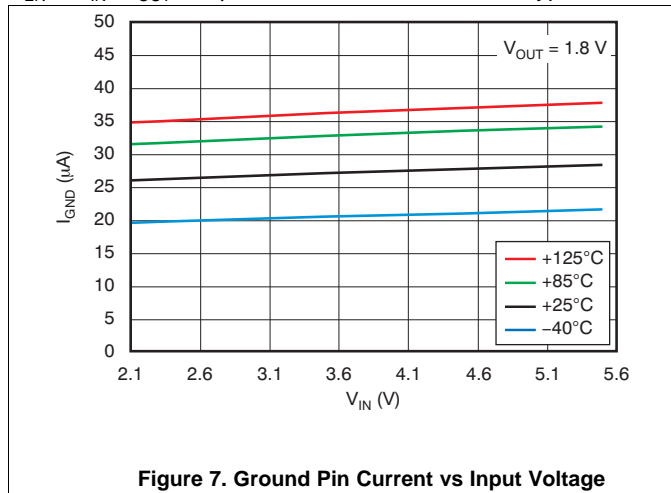


Figure 7. Ground Pin Current vs Input Voltage

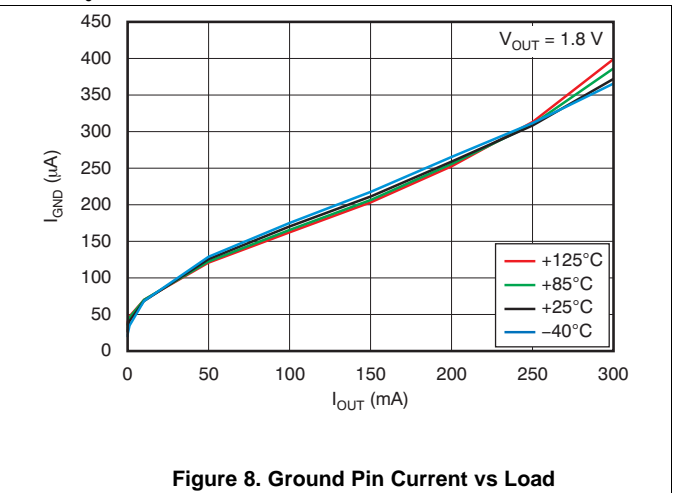


Figure 8. Ground Pin Current vs Load

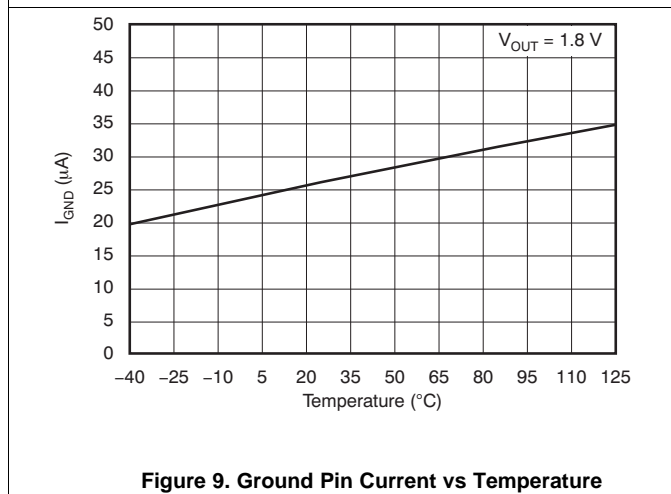


Figure 9. Ground Pin Current vs Temperature

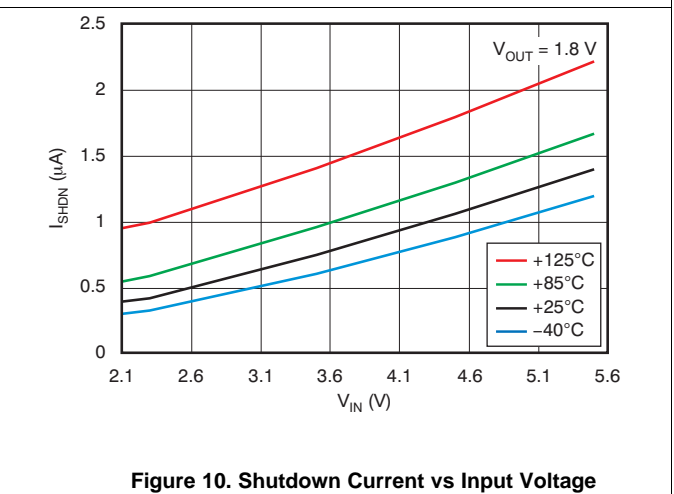


Figure 10. Shutdown Current vs Input Voltage

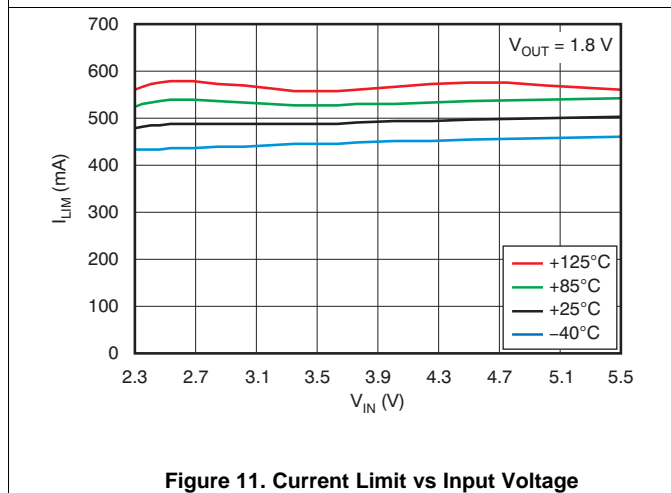


Figure 11. Current Limit vs Input Voltage

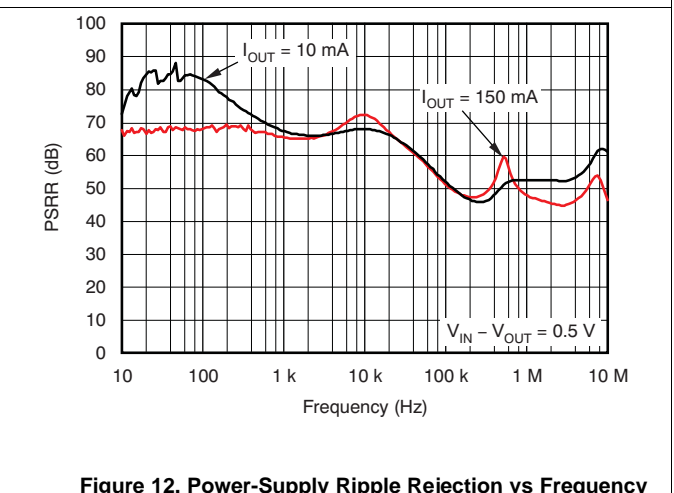


Figure 12. Power-Supply Ripple Rejection vs Frequency

Typical Characteristics (continued)

Over operating temperature range ($T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$), $V_{IN} = V_{OUT(nom)} + 0.5\text{ V}$ or 2 V , whichever is greater; $I_{OUT} = 10\text{ mA}$, $V_{EN} = V_{IN}$, $C_{OUT} = 1\text{ }\mu\text{F}$, unless otherwise noted. Typical values are at $T_J = 25^\circ\text{C}$.



Figure 13. Power-Supply Ripple Rejection vs Input Voltage

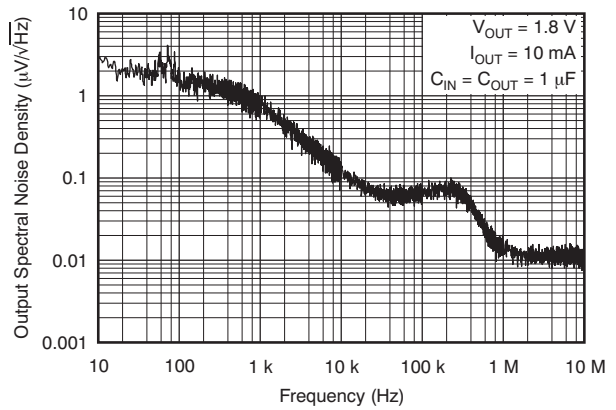


Figure 14. Output Spectral Noise Density vs Frequency



Figure 15. Load Transient Response



Figure 16. Load Transient Response



Figure 17. Load Transient Response



Figure 18. Load Transient Response

Typical Characteristics (continued)

Over operating temperature range ($T_J = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$), $V_{IN} = V_{OUT(nom)} + 0.5\text{ V}$ or 2 V , whichever is greater; $I_{OUT} = 10\text{ mA}$, $V_{EN} = V_{IN}$, $C_{OUT} = 1\ \mu\text{F}$, unless otherwise noted. Typical values are at $T_J = 25^{\circ}\text{C}$.



7 Detailed Description

7.1 Overview

The TLV702-Q1 series of low-dropout (LDO) linear regulators are low quiescent current devices with excellent line and load transient performance. These LDOs are designed for power-sensitive applications. A precision bandgap and error amplifier provides overall 2% accuracy. Low output noise, very high power-supply rejection ratio (PSRR), and low dropout voltage make this series of devices ideal for most battery-operated handheld equipment. All device versions have integrated thermal shutdown, current limit, and undervoltage lockout (UVLO) protections.

7.2 Functional Block Diagrams

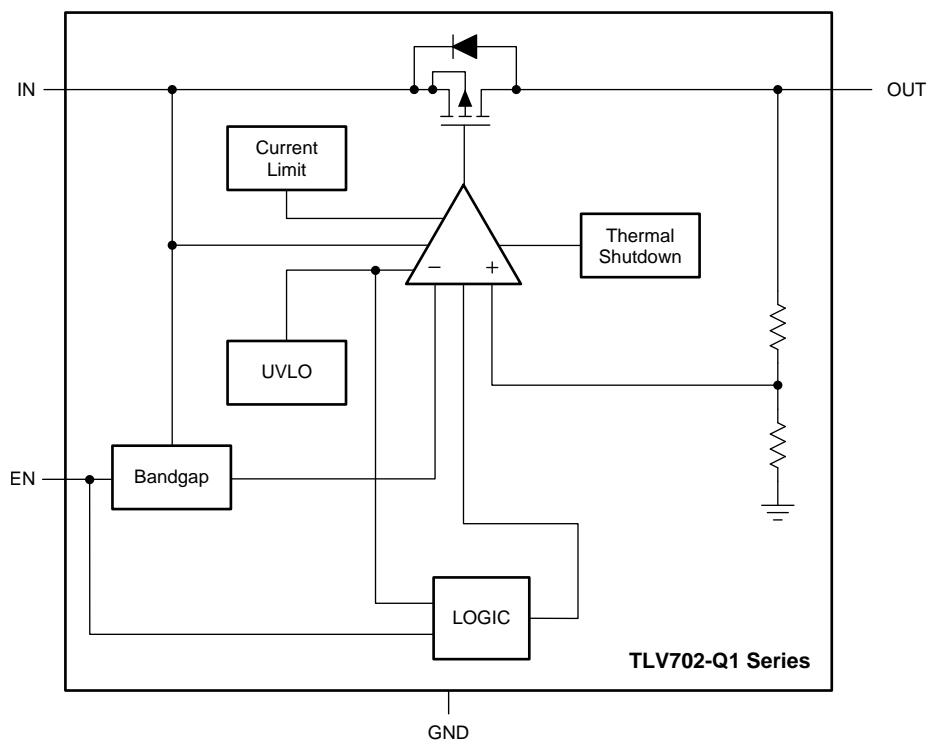


Figure 23. TLV702-Q1 Block Diagram

7.3 Feature Description

7.3.1 Internal Current Limit

The TLV702-Q1 internal current limit protection helps to protect the regulator during fault conditions. During current limit operation, the output sources a fixed amount of current that is largely independent of the output voltage. In such a case, the output voltage is not regulated, and is $V_{OUT} = I_{CL} \times R_{LOAD}$. The PMOS pass transistor dissipates $(V_{IN} - V_{OUT}) \times I_{CL}$ until thermal shutdown is triggered and the device turns off. As the device cools, the device is turned on by the internal thermal shutdown circuit. If the fault condition continues, the device cycles between current limit operation and thermal shutdown. See [Thermal Consideration](#) for more details.

The PMOS pass element in the TLV702-Q1 has a built-in body diode that conducts current when the voltage at the OUT pin exceeds the voltage at IN. This current is not limited; if extended reverse-voltage operation is anticipated, externally limit the output current to 5% of the rated I_{OUT} specification.

Feature Description (continued)

7.3.2 Shutdown

The enable pin (EN) is active high. The device is enabled when voltage at EN pin exceeds 0.9 V. The device is turned off when the EN pin is held at less than 0.4 V. When shutdown capability is not required, connect the EN pin to the IN pin.

7.3.3 Dropout Voltage

The TLV702-Q1 uses a PMOS pass transistor to achieve low dropout. When $(V_{IN} - V_{OUT})$ is less than the dropout voltage (V_{DO}), the PMOS pass device is in the linear (triode) region of operation. The input-to-output resistance is equal to the drain-source on-state resistance ($R_{DS(on)}$) of the PMOS pass element. V_{DO} scales approximately with output current because the PMOS device behaves as a resistor in dropout.

As with any linear regulator, PSRR and transient response are degraded as $(V_{IN} - V_{OUT})$ approaches dropout. This effect is shown in [Figure 13](#).

7.3.4 Undervoltage Lockout

The TLV702-Q1 uses a UVLO circuit to keep the output shut off until internal circuitry is operating properly.

7.4 Device Functional Modes

7.4.1 Normal Operation

The device regulates to the nominal output voltage under the following conditions:

- The input voltage is greater than the nominal output voltage added to the dropout voltage.
- The output current is less than the current limit.
- The input voltage is greater than the UVLO voltage.

7.4.2 Dropout Operation

If the input voltage is less than the nominal output voltage plus the specified dropout voltage, but all other conditions are met for normal operation, the device operates in dropout mode. In this condition, the output voltage is the same as the input voltage minus the dropout voltage. The transient performance of the device is significantly degraded because the pass device is in a triode state and no longer regulates the output voltage of the LDO. Line or load transients in dropout may result in large output voltage deviations.

[Table 1](#) lists the conditions that lead to the different modes of operation.

Table 1. Device Functional Mode Comparison

OPERATING MODE	PARAMETER	
	V_{IN}	I_{OUT}
Normal mode	$V_{IN} > V_{OUT(nom)} + V_{DO}$	$I_{OUT} < I_{CL}$
Dropout mode	$V_{IN} < V_{OUT(nom)} + V_{DO}$	$I_{OUT} < I_{CL}$
Current limit	$V_{IN} > UVLO$	$I_{OUT} > I_{CL}$

8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The TLV702-Q1 belongs to a new family of next-generation value LDO regulators. These devices consume low quiescent current and deliver excellent line and load transient performance. These characteristics, combined with low noise and very good PSRR with little ($V_{IN} - V_{OUT}$) headroom, make this family of devices ideal for portable RF applications. This family of regulators offers current limit and thermal protection, and is specified from -40°C to $+125^{\circ}\text{C}$.

8.2 Typical Application

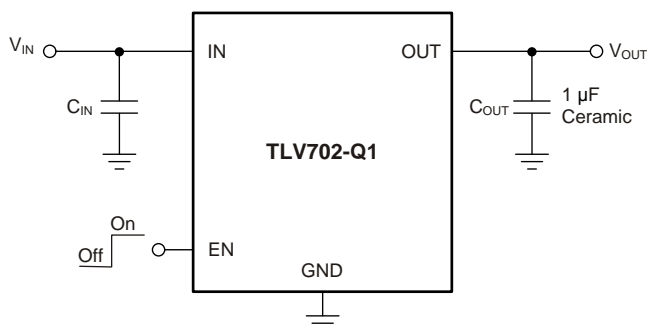


Figure 24. Typical Application Circuit

8.2.1 Design Requirements

Table 2 lists the design parameters.

Table 2. Design Parameters

PARAMETER	DESIGN REQUIREMENT
Input voltage	2.5 V to 3.3 V
Output voltage	1.8 V
Output current	100 mA

8.2.2 Detailed Design Procedure

8.2.2.1 Input and Output Capacitor Requirements

1- μF X5R- and X7R-type ceramic capacitors are recommended because these capacitors have minimal variation in value and equivalent series resistance (ESR) over temperature.

However, the TLV702-Q1 is designed to be stable with an *effective capacitance* of 0.1 μF or larger at the output. Thus, the device is stable with capacitors of other dielectric types as well, as long as the effective capacitance under operating bias voltage and temperature is greater than 0.1 μF . This effective capacitance refers to the capacitance that the LDO sees under operating bias voltage and temperature conditions; that is, the capacitance after taking both bias voltage and temperature derating into consideration. In addition to allowing the use of lower-cost dielectrics, this capability of being stable with 0.1- μF effective capacitance also enables the use of smaller footprint capacitors that have higher derating in size- and space-constrained applications.

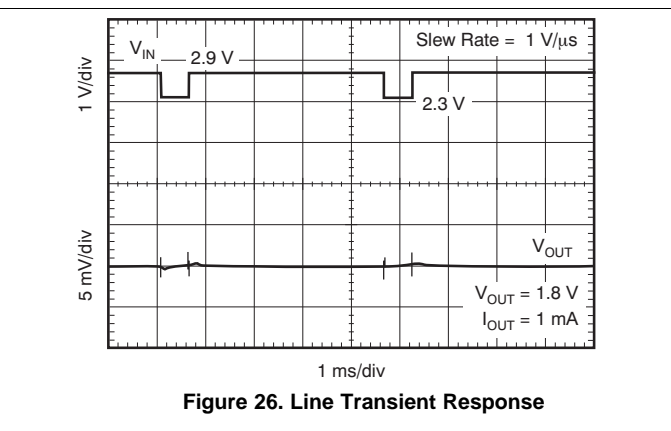
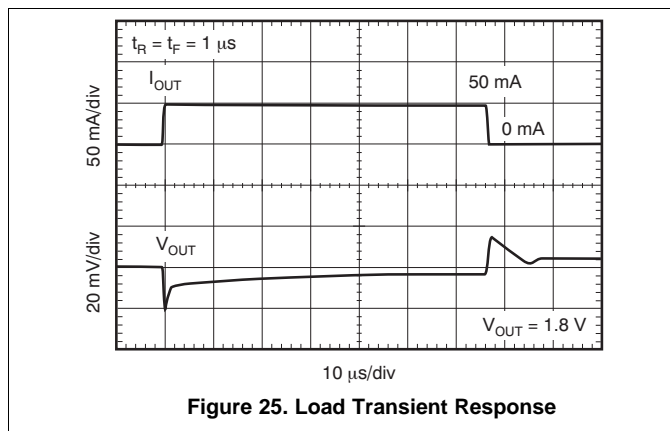
Using a 0.1- μF rated capacitor at the output of the LDO does not ensure stability because the effective capacitance under the specified operating conditions must not be less than 0.1 μF . Maximum ESR should be less than 200 m Ω .

Although an input capacitor is not required for stability, it is good analog design practice to connect a 0.1- μF to 1- μF , low ESR capacitor across the IN pin and GND pin of the regulator. This capacitor counteracts reactive input sources and improves transient response, noise rejection, and ripple rejection. A higher-value capacitor may be necessary if large, fast rise-time load transients are anticipated, or if the device is not located close to the power source. If source impedance is more than 2 Ω , a 0.1- μF input capacitor may be necessary for stability.

8.2.2.2 Transient Response

As with any regulator, increasing the size of the output capacitor reduces overshoot and undershoot magnitude, but increases the duration of the transient response.

8.2.3 Application Curves



9 Power Supply Recommendations

Connect a low output impedance power supply directly to the IN pin of the TLV702-Q1. Inductive impedances between the input supply and the IN pin can create significant voltage excursions at the IN pin during start-up or load transient events.

9.1 Power Dissipation

The ability to remove heat from the die is different for each package type, presenting different considerations in the printed-circuit-board (PCB) layout. The PCB area around the device that is free of other components moves the heat from the device to the ambient air.

Refer to [Thermal Information](#) for thermal performance on the TLV702-Q1 evaluation module (EVM). The EVM is a two-layer board with two ounces of copper per side.

Power dissipation depends on input voltage and load conditions. Power dissipation (P_D) is equal to the product of the output current and the voltage drop across the output pass element, as shown in [Equation 1](#).

$$P_D = (V_{IN} - V_{OUT}) \times I_{OUT} \quad (1)$$

10 Layout

10.1 Layout Guidelines

Place the input and output capacitors as close to the device pins as possible. To improve ac performance such as PSRR, output noise, and transient response, design the board with separate ground planes for V_{IN} and V_{OUT} , with the ground plane connected only at the GND pin of the device. In addition, connect the ground connection for the output capacitor directly to the GND pin of the device. High-ESR capacitors may degrade PSRR performance.

10.1.1 Thermal Consideration

Thermal protection disables the output when the junction temperature rises to approximately 165°C, allowing the device to cool. When the junction temperature cools to approximately 145°C, the output circuitry is again enabled. Depending on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit may cycle on and off. This cycling limits the dissipation of the regulator, protecting it from damage as a result of overheating.

Any tendency to activate the thermal protection circuit indicates excessive power dissipation or an inadequate heatsink. For reliable operation, limit junction temperature to 125°C maximum.

To estimate the margin of safety in a complete design (including heatsink), increase the ambient temperature until the thermal protection is triggered; use worst-case loads and signal conditions.

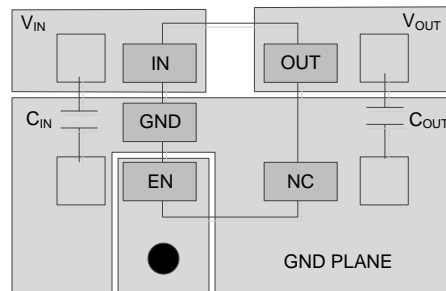
The internal protection circuitry of the TLV702-Q1 is designed to protect against overload conditions but is not intended to replace proper heatsinking. Continuously running the TLV702-Q1 into thermal shutdown degrades device reliability.

Layout Guidelines (continued)

10.1.2 Package Mounting

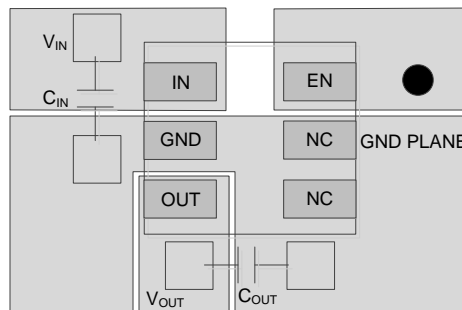
Solder pad footprint recommendations for the TLV702-Q1 are available from the TI website at www.ti.com. The recommended layout examples for the DDC and DSE packages are shown in [Figure 27](#) and [Figure 28](#), respectively.

10.2 Layout Examples



● Represents via used for application specific connections

Figure 27. Layout Example for the DDC and DBV Packages



● Represents via used for application specific connections

Figure 28. Layout Example for the DSE Package

11 Device and Documentation Support

11.1 Device Support

11.1.1 Development Support

11.1.1.1 Spice Models

Computer simulation of circuit performance using SPICE is often useful when analyzing the performance of analog circuits and systems. A SPICE model for the TLV702 is available through the product folders under *Tools & Software*.

11.1.2 Device Nomenclature

Table 3. Ordering Information⁽¹⁾

PRODUCT	V _{OUT} ⁽²⁾
TLV702xx yyyz	XX is nominal output voltage (for example, 28 = 2.8 V). YYY is the package designator. Z is tape and reel quantity (R = 3000, T = 250).

- (1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or visit the device product folder at www.ti.com.
- (2) Output voltages from 1.2 V to 4.8 V in 50-mV increments are available. Contact factory for details and availability.

11.2 Documentation Support

11.2.1 Related Documentation

For related documentation see the following:

Texas Instruments, [Using the TLV700xxEVM-503 user's guide](#)

11.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.4 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.5 Trademarks

E2E is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

11.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

11.7 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLV702125QDBVRQ1	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU SN NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	1M57
TLV702125QDBVRQ1.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1M57
TLV702125QDBVRQ1.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1M57
TLV70212QDBVRQ1	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	1B5H
TLV70212QDBVRQ1.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1B5H
TLV70212QDBVRQ1.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1B5H
TLV70212QDSERQ1	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	H9
TLV70212QDSERQ1.A	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	H9
TLV70212QDSERQ1.B	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	H9
TLV70213QDSERQ1	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	H8
TLV70213QDSERQ1.A	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	H8
TLV70213QDSERQ1.B	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	H8
TLV70215QDBVRQ1	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	1B6H
TLV70215QDBVRQ1.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1B6H
TLV70215QDBVRQ1.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1B6H
TLV70215QDSERQ1	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	HB
TLV70215QDSERQ1.A	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	HB
TLV70215QDSERQ1.B	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	HB
TLV70218QDBVRQ1	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU SN NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	1B7H
TLV70218QDBVRQ1.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1B7H
TLV70218QDBVRQ1.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1B7H
TLV70218QDSERQ1	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	HC
TLV70218QDSERQ1.A	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	HC
TLV70218QDSERQ1.B	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	HC
TLV70225QDSERQ1	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	G7
TLV70225QDSERQ1.A	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	G7
TLV70225QDSERQ1.B	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	G7
TLV70227QDBVRQ1	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	1B8H

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLV70227QDBVRQ1.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1B8H
TLV70227QDBVRQ1.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1B8H
TLV70227QDSERQ1	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	H7
TLV70227QDSERQ1.A	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	H7
TLV70227QDSERQ1.B	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	H7
TLV70228QDBVRQ1	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	1B9H
TLV70228QDBVRQ1.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1B9H
TLV70228QDBVRQ1.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1B9H
TLV70228QDDCRQ1	Active	Production	SOT-23- THIN (DDC) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SJV
TLV70228QDDCRQ1.A	Active	Production	SOT-23- THIN (DDC) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SJV
TLV70228QDDCRQ1.B	Active	Production	SOT-23- THIN (DDC) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SJV
TLV70228QDSERQ1	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HD
TLV70228QDSERQ1.A	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HD
TLV70228QDSERQ1.B	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HD
TLV70229QDBVRQ1	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	1BAH
TLV70229QDBVRQ1.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	1BAH
TLV70229QDBVRQ1.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	1BAH
TLV70229QDSERQ1	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	H1
TLV70229QDSERQ1.A	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	H1
TLV70229QDSERQ1.B	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	H1
TLV70230QDBVRQ1	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	1MQ7
TLV70230QDBVRQ1.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	1MQ7
TLV70230QDBVRQ1.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	1MQ7
TLV70230QDSERQ1	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	HE
TLV70230QDSERQ1.A	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	HE
TLV70230QDSERQ1.B	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	HE
TLV70231QDSERQ1	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	HF
TLV70231QDSERQ1.A	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	HF

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLV70231QDSERQ1.B	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	HF
TLV70232QDSERQ1	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	HG
TLV70232QDSERQ1.A	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	HG
TLV70232QDSERQ1.B	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	HG
TLV70233QDBVRQ1	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU SN NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	1BBH
TLV70233QDBVRQ1.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1BBH
TLV70233QDBVRQ1.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1BBH
TLV70233QDSERQ1	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	H2
TLV70233QDSERQ1.A	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	H2
TLV70233QDSERQ1.B	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	H2
TLV70236QDSERQ1	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	H3
TLV70236QDSERQ1.A	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	H3
TLV70236QDSERQ1.B	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	H3
TLV70245QDSERQ1	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	HH
TLV70245QDSERQ1.A	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	HH
TLV70245QDSERQ1.B	Active	Production	WSON (DSE) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	HH

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TLV702-Q1 :

- Catalog : [TLV702](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV702125QDBVRQ1	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TLV702125QDBVRQ1	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TLV70212QDBVRQ1	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TLV70212QDBVRQ1	SOT-23	DBV	5	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TLV70212QDSERQ1	WSON	DSE	6	3000	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TLV70213QDSERQ1	WSON	DSE	6	3000	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TLV70215QDBVRQ1	SOT-23	DBV	5	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TLV70215QDSERQ1	WSON	DSE	6	3000	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TLV70218QDBVRQ1	SOT-23	DBV	5	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TLV70218QDBVRQ1	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TLV70218QDSERQ1	WSON	DSE	6	3000	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TLV70225QDSERQ1	WSON	DSE	6	3000	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TLV70227QDBVRQ1	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TLV70227QDBVRQ1	SOT-23	DBV	5	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TLV70227QDSERQ1	WSON	DSE	6	3000	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TLV70228QDBVRQ1	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

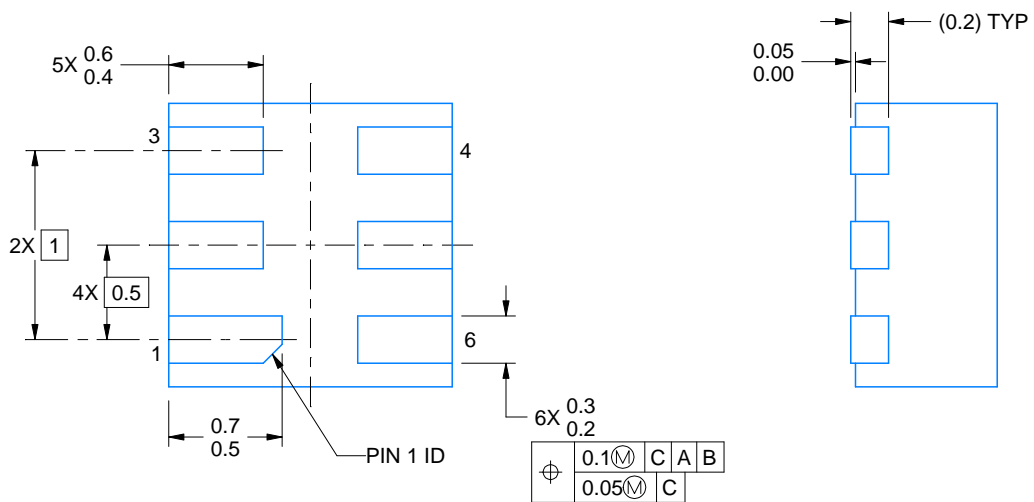
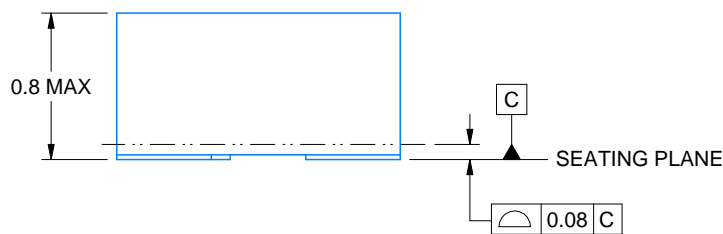
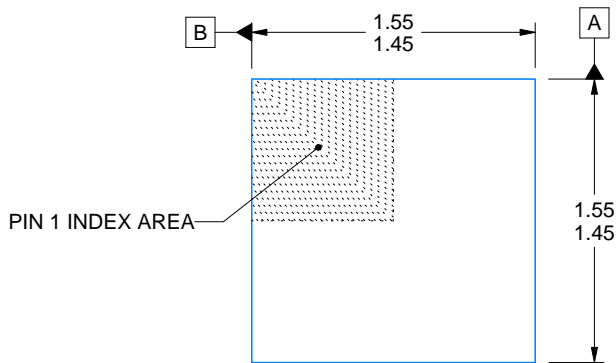
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV70228QDBVRQ1	SOT-23	DBV	5	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TLV70228QDDCRQ1	SOT-23-THIN	DDC	5	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TLV70228QDSERQ1	WSO	DSE	6	3000	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TLV70229QDBVRQ1	SOT-23	DBV	5	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TLV70229QDSERQ1	WSO	DSE	6	3000	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TLV70230QDBVRQ1	SOT-23	DBV	5	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TLV70230QDSERQ1	WSO	DSE	6	3000	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TLV70231QDSERQ1	WSO	DSE	6	3000	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TLV70232QDSERQ1	WSO	DSE	6	3000	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TLV70233QDBVRQ1	SOT-23	DBV	5	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TLV70233QDSERQ1	WSO	DSE	6	3000	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TLV70236QDSERQ1	WSO	DSE	6	3000	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2
TLV70245QDSERQ1	WSO	DSE	6	3000	179.0	8.4	1.8	1.8	1.0	4.0	8.0	Q2

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV702125QDBVRQ1	SOT-23	DBV	5	3000	210.0	185.0	35.0
TLV702125QDBVRQ1	SOT-23	DBV	5	3000	210.0	185.0	35.0
TLV70212QDBVRQ1	SOT-23	DBV	5	3000	210.0	185.0	35.0
TLV70212QDBVRQ1	SOT-23	DBV	5	3000	183.0	183.0	20.0
TLV70212QDSERQ1	WSON	DSE	6	3000	200.0	183.0	25.0
TLV70213QDSERQ1	WSON	DSE	6	3000	200.0	183.0	25.0
TLV70215QDBVRQ1	SOT-23	DBV	5	3000	183.0	183.0	20.0
TLV70215QDSERQ1	WSON	DSE	6	3000	200.0	183.0	25.0
TLV70218QDBVRQ1	SOT-23	DBV	5	3000	183.0	183.0	20.0
TLV70218QDBVRQ1	SOT-23	DBV	5	3000	210.0	185.0	35.0
TLV70218QDSERQ1	WSON	DSE	6	3000	200.0	183.0	25.0
TLV70225QDSERQ1	WSON	DSE	6	3000	200.0	183.0	25.0
TLV70227QDBVRQ1	SOT-23	DBV	5	3000	210.0	185.0	35.0
TLV70227QDBVRQ1	SOT-23	DBV	5	3000	183.0	183.0	20.0
TLV70227QDSERQ1	WSON	DSE	6	3000	200.0	183.0	25.0
TLV70228QDBVRQ1	SOT-23	DBV	5	3000	210.0	185.0	35.0
TLV70228QDBVRQ1	SOT-23	DBV	5	3000	183.0	183.0	20.0
TLV70228QDDCRQ1	SOT-23-THIN	DDC	5	3000	213.0	191.0	35.0

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV70228QDSERQ1	WSON	DSE	6	3000	200.0	183.0	25.0
TLV70229QDBVRQ1	SOT-23	DBV	5	3000	183.0	183.0	20.0
TLV70229QDSERQ1	WSON	DSE	6	3000	200.0	183.0	25.0
TLV70230QDBVRQ1	SOT-23	DBV	5	3000	183.0	183.0	20.0
TLV70230QDSERQ1	WSON	DSE	6	3000	200.0	183.0	25.0
TLV70231QDSERQ1	WSON	DSE	6	3000	200.0	183.0	25.0
TLV70232QDSERQ1	WSON	DSE	6	3000	200.0	183.0	25.0
TLV70233QDBVRQ1	SOT-23	DBV	5	3000	183.0	183.0	20.0
TLV70233QDSERQ1	WSON	DSE	6	3000	200.0	183.0	25.0
TLV70236QDSERQ1	WSON	DSE	6	3000	200.0	183.0	25.0
TLV70245QDSERQ1	WSON	DSE	6	3000	200.0	183.0	25.0



4220552/B 01/2024

NOTES:

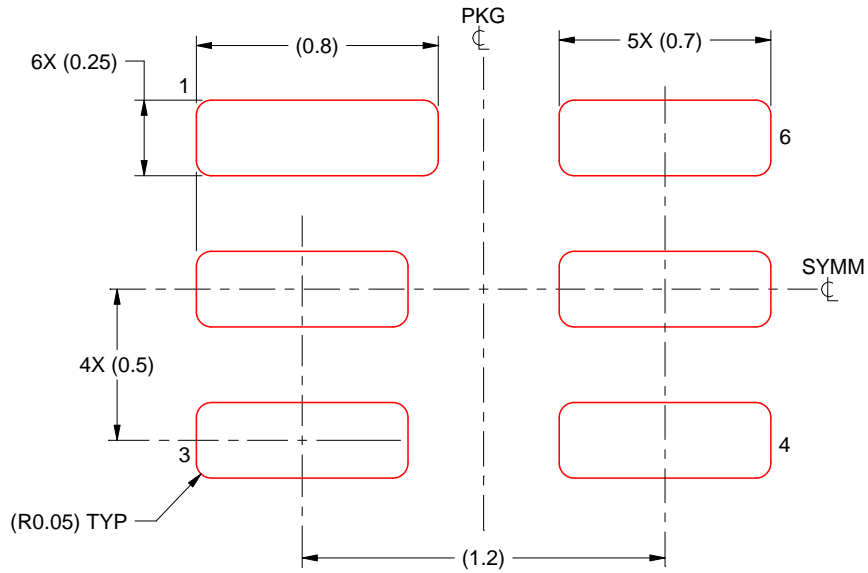
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

EXAMPLE STENCIL DESIGN

DSE0006A

WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:40X

NOTES: (continued)

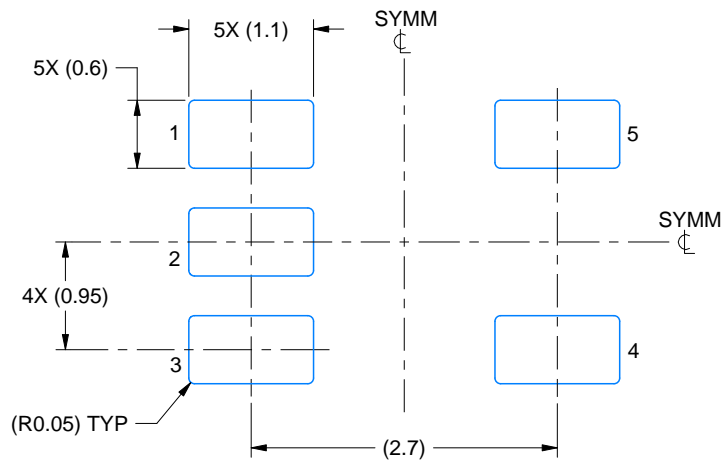
4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

EXAMPLE BOARD LAYOUT

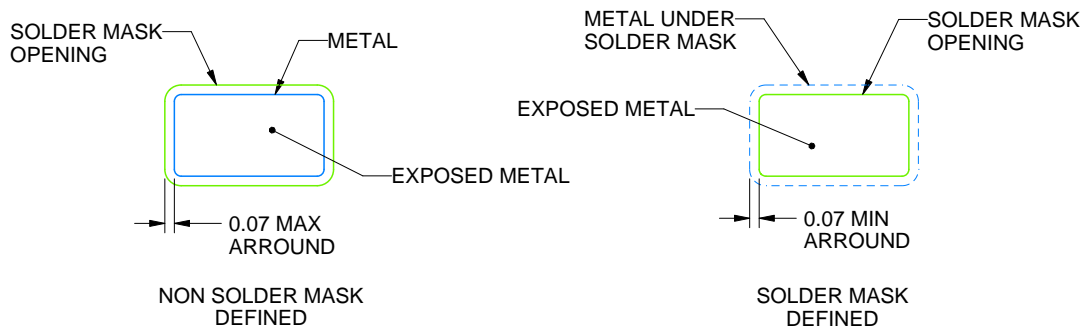
DDC0005A

SOT-23 - 1.1 max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPLODED METAL SHOWN
SCALE:15X



SOLDERMASK DETAILS

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NOTES: (continued)

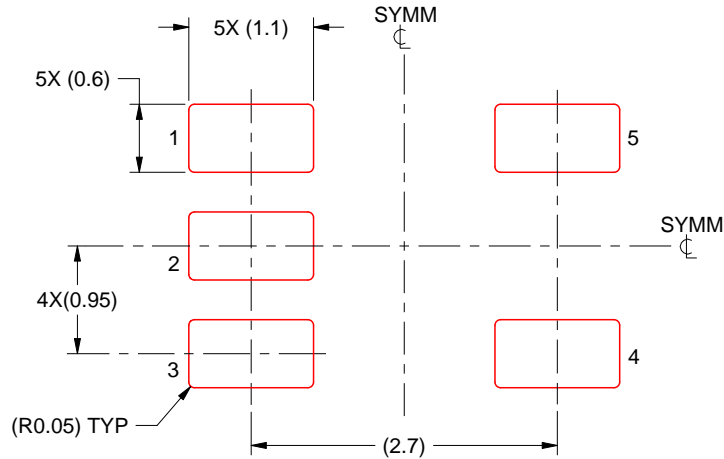
- 4. Publication IPC-7351 may have alternate designs.
- 5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DDC0005A

SOT-23 - 1.1 max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:15X

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NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
7. Board assembly site may have different recommendations for stencil design.

EXAMPLE BOARD LAYOUT

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

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NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

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NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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